## **CGY1032**

# 1 GHz, 32 dB gain GaAs push-pull amplifier Rev. 1 — 10 February 2011

**Product data sheet** 

#### **Product profile** 1.

#### 1.1 General description

Hybrid amplifier module in a SOT115J package, operating at a supply voltage of 24 V Direct Current (DC), employing Heterojunction Field Effect Transistor (HFET) GaAs dies.

#### 1.2 Features and benefits

- Excellent linearity, stability and reliability
- Extremely low noise
- Excellent return loss properties
- Rugged construction
- Unconditionally stable
- Thermally optimized design
- Superior levels of ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)
- Integrated ring wave surge protection
- Power gain is specified for both 870 MHz and 1003 MHz bandwidth

#### 1.3 Applications

CATV systems operating in the 40 MHz to 1003 MHz frequency range

#### 1.4 Quick reference data

Quick reference data

Bandwidth 40 MHz to 1003 MHz;  $V_B = 24 \text{ V (DC)}$ ;  $Z_S = Z_L = 75 \Omega$ ;  $T_{mb} = 35 \text{ °C}$ ; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	f = 45 MHz	30.0	31.0	32.0	dB
		f = 870 MHz	31.4	32.4	33.4	dB
		f = 1003 MHz	32.0	33.0	34.0	dB
CTB	composite triple beat	$V_o = 44 \text{ dBmV}$	[1] -	-62	-	dBc
CCN	carrier-to-composite noise	$V_o = 44 \text{ dBmV}$	<u>[1]</u> -	63	-	dBc
I <sub>tot</sub>	total current		[2] _	265	280	mA

<sup>[1] 79</sup> NTSC channels [f = 55.25 MHz to 547.25 MHz] + 75 digital channels [f = 547.25 MHz to 1003 MHz] (-6 dB offset); flat output level.



<sup>[2]</sup> Direct Current (DC).

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## 2. Pinning information

Table 2. Pinning

10010 =1	9	
Pin	Description	Simplified outline Graphic symbol
1	input	
2, 3	common	1 3 5 7 9
5	+V <sub>B</sub>	
7, 8	common	2378
9	output	
		•

## 3. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
CGY1032	-	rectangular single-ended package; aluminium flange; 2 vertical mounting holes; $2 \times 6-32$ UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads	SOT115J		

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{B}$	supply voltage			-	30	V
$V_{i(RF)}$	RF input voltage	single tone		-	75	dBmV
V <sub>ESD</sub>	electrostatic discharge voltage	Human Body Model (HBM); According JEDEC standard 22-A114E	[1]	-	2000	V
		Biased; According IEC61000-4-2		-	2000	V
T <sub>stg</sub>	storage temperature			-40	+100	°C
$T_{mb}$	mounting base temperature			-20	+100	°C

<sup>[1]</sup> The value of 2000 V corresponds to a class 2 classification.

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#### 5. Characteristics

Table 5. Characteristics

Bandwidth 40 MHz to 1003 MHz;  $V_B = 24 \text{ V (DC)}$ ;  $Z_S = Z_L = 75 \Omega$ ;  $T_{mb} = 35 \text{ °C}$ ; unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Gp	power gain	f = 45 MHz		30.0	31.0	32.0	dB
		f = 870 MHz		31.4	32.4	33.4	dB
		f = 1003 MHz		32.0	33.0	34.0	dB
SL <sub>sl</sub>	slope straight line	f = 45 MHz to 1003 MHz	[1]	1.05	1.8	2.55	dB
FL	flatness of frequency response	f = 45 MHz to 1003 MHz	[2]	-	-	0.85	dB
RLin	input return loss	f = 45 MHz to 200 MHz		20	-	-	dB
		f = 200 MHz to 550 MHz		20	-	-	dB
		f = 550 MHz to 870 MHz		20	-	-	dB
		f = 870 MHz to 914 MHz		20	-	-	dB
		f = 914 MHz to 1003 MHz		16	-	-	dB
RLout	output return loss	f = 45 MHz to 200 MHz		18	-	-	dB
		f = 200 MHz to 550 MHz		18	-	-	dB
		f = 550 MHz to 870 MHz		18	-	-	dB
		f = 870 MHz to 914 MHz		18	-	-	dB
		f = 914 MHz to 1003 MHz		16	-	-	dB
NF	noise figure	f = 50 MHz		-	3.4	4.0	dB
		f = 1003 MHz		-	4.4	4.9	dB
I <sub>tot</sub>	total current		[3]	-	265	280	mA
79 NTSC	channels + 75 digital channels						
СТВ	composite triple beat	$V_0 = 44 \text{ dBmV}$	[4]	-	-62	-	dBc
CSO	composite second-order distortion	$V_0 = 44 \text{ dBmV}$	[4]	-	-64	-	dBc
Xmod	cross modulation	$V_0 = 44 \text{ dBmV}$	[4]	-	-58	-	dB
CCN	carrier-to-composite noise	V <sub>o</sub> = 44 dBmV	[4]	-	63	-	dBc
79 NTSC	channels						
СТВ	composite triple beat	$V_0 = 44 \text{ dBmV}$	<u>[5]</u>	-	-	-62	dBc
CSO	composite second-order distortion	$V_0 = 44 \text{ dBmV}$	<u>[5]</u>	-	-	-64	dBc
Xmod	cross modulation	$V_0 = 44 \text{ dBmV}$	<u>[5]</u>	-	-58	-	dB
98 PAL 0	channels						
СТВ	composite triple beat	$V_0 = 44 \text{ dBmV}$	[6]	-	-68	-	dBc
CSO	composite second-order distortion	$V_0 = 44 \text{ dBmV}$	[6]	-	-66	-	dBc
Xmod	cross modulation	$V_0 = 44 \text{ dBmV}$	[6]	-	-58	-	dB

<sup>[1]</sup>  $G_p$  at 1003 MHz minus  $G_p$  at 45 MHz.

<sup>[2]</sup> Flatness is defined as peak deviation to straight line.

<sup>[3]</sup> Direct Current (DC).

<sup>[4] 79</sup> NTSC channels [f = 55.25 MHz to 547.25 MHz] + 75 digital channels [f = 547.25 MHz to 1003 MHz] (-6 dB offset); flat output level.

<sup>[5] 79</sup> NTSC channels [f = 55.25 MHz to 550 MHz]; flat output level.

<sup>[6] 98</sup> PAL channels [f = 49.75 MHz to 847.25 MHz]; flat output level.

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## 6. Package outline

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads

SOT115J

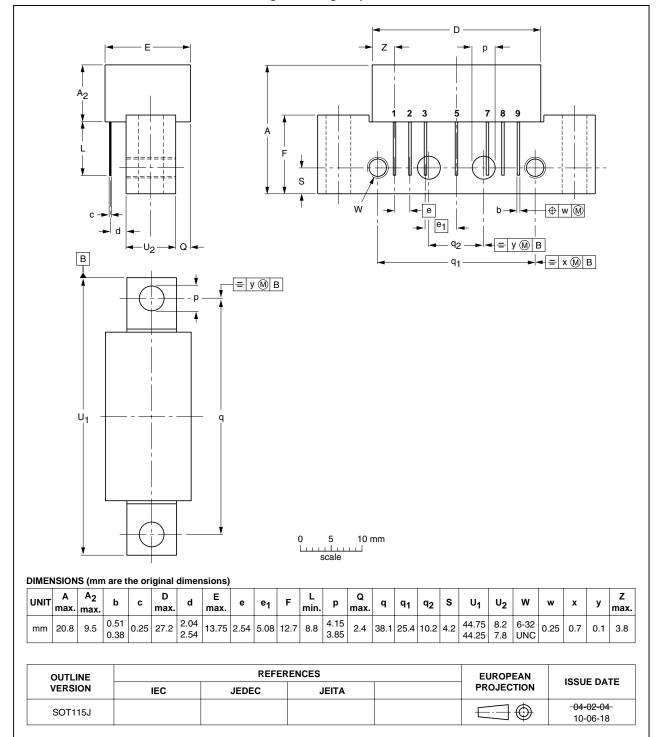


Fig 1. Package outline SOT115J

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## 7. Abbreviations

Table 6. Abbreviations

Acronym	Description
CATV	Community Antenna TeleVision
ESD	ElectroStatic Discharge
GaAs	Gallium Arsenide
NTSC	National Television Standard Committee
PAL	Phase Alternating Line
RF	Radio Frequency
UNC	UNified Coarse

## 8. Revision history

#### Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
CGY1032 v.1	20110210	Product data sheet	-	-

#### 1 GHz, 32 dB gain GaAs push-pull amplifier

#### 9. Legal information

#### 9.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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- [2] The term 'short data sheet' is explained in section "Definitions"
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